• PATENT APPLICATION

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FORM PTO-1449	ATTY. DKT NO.	01-493	SER. NO.	
	APPLICANT	FUKUDA et al.		
	FILING DATE	October 21, 2003	GROUP	

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
TTU	4,636,825	Jan. 13, 1987	Baynes		
TW	4,948,754	Aug. 14, 1990	Kondo et al.		
177/	5,192,989	Mar. 9, 1993	Matsushita et al.		
ME	5,412,239	May 2, 1995	Williams		
TOW	5,672,894	Sep. 30. 1997	Maeda et al.		

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							TRANSLATIO	N
	DOCUMENT NUMBER	DATE	COUNTRY	NAME	CLASS	SUB CLASS	YES	NO
JIN	JP-A-H07-263665 (Discussed in page 1 of the spec.)	10/13/95	JAPAN				X (Abstract)	
M	JP-A-H03-239369	10/24/91	JAPAN				X (Abstract)	

* Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at http://www1.ipdLjpo.go.jp/PA1/cgi-bin/PA1INDEX.

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

TON		Hazel Schofield et al., "Assembly of FlipFET™ Devices", International Rectifier, AN-1011, 5/22/2000, pp.1-6
TW		"International Rectifier", IRF6150, PD-93943, pp. 1-3
M	/	Hazel Schofield et al., "FlipFETTM MOSFET Design for High Volume SMT Assembly", International Rectifier, pp.1-6
EXAMINER	/	DATE CONSIDERED
L <i>C</i>	1	1/31/2005
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